# NSN 5961-01-413-6275

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# Inclosure Material:

Plastic

## **Overall Length:**

Between 0.1102 inches and 0.1197 inches

## Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-236ab

### Mounting Method:

Terminal

### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

-80.0 collector to base voltage/static/emitter open and -80.0 collector to emitter voltage/static/base open and -4.0 emitter to base voltage,

static, collector open

## **Current Rating Per Characteristic:**

-500.00 milliamperes source cutoff current

#### Transfer Ratio:

50.0 static forward current transfer ratio, common-emitter

### **Special Features:**

Junction pattern arrangement: pnp

#### Terminal Type And Quantity:

3 bonding pad

Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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